



## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT:

T. Inui et al.

U.S. SERIAL NO:

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EXAMINER: M. Song

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FOR:

CRYSTAL GROWTH APPARATUS AND CRYSTAL GROWTH

METHOD FOR SEMICONDUCTOR THIN FILM

## **CERTIFICATE OF FACSIMILE TRANSMISSION**

I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being transmitted by facsimile to the U.S. Patent & Trademark Office by facsimile number 571-273-8300 on <u>January 10, 2007</u>.

Steven M. Jensen

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

## **AMENDMENT**

Applicants are in receipt of the Office Action dated October 10, 2006 of the above-referenced application. Please amend the application as follows:

Amendments to the claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 5 of this paper.